

Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	30	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current Continuous (V_{GS} = 10V, T_C < 163°C)	80	А
I _D	Continuous ($V_{GS} = 5V$, $T_C < 162^{\circ}C$)	80	Α
	Continuous (V _{GS} = 10V, T _C = 25°C, with $R_{\theta JA}$ = 43°C/W)	31	Α
	Pulsed	Figure 4	A
E _{AS}	SinglePulseAvalancheEnergy (Note1)	947	mJ
D	Power Dissipation	254	W
P _D	Derate above 25°C	1.7	W/ºC
T _J , T _{STG}	Operating and Storage Temperature	-55 to +175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case	0.59	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient (Note 2)	62	°C/W
$R_{ hetaJA}$	Thermal Resistance Junction to Ambient TO-263,1in ² copper pad area	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8860	FDB8860	TO-263AB	330mm	24mm	800units

Electrical Characteristics T_J = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 1mA, V_{GS} = 0V$	30	-	-	V
I	Zero Gate Voltage Drain Current	$V_{DS} = 24V$	-	-	1	μA
DSS	Zelo Gale Voltage Dialit Guitent	$V_{GS} = 0V$ $T_J = 150^{\circ}C$	-	-	250	μΛ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1	1.7	3	V
		$I_{D} = 80A, V_{GS} = 10V$	-	1.6	2.3	
		$I_{D} = 80A, V_{GS} = 5V$	-	1.9	2.6	
R _{DS(ON)}	Drain to Source On Resistance	$I_{D} = 80A, V_{GS} = 4.5V$	-	2.1	2.7	mΩ
		I _D = 80A, V _{GS} = 10V, T _J = 175°C	-	2.5	3.6	

Dynamic Characteristics

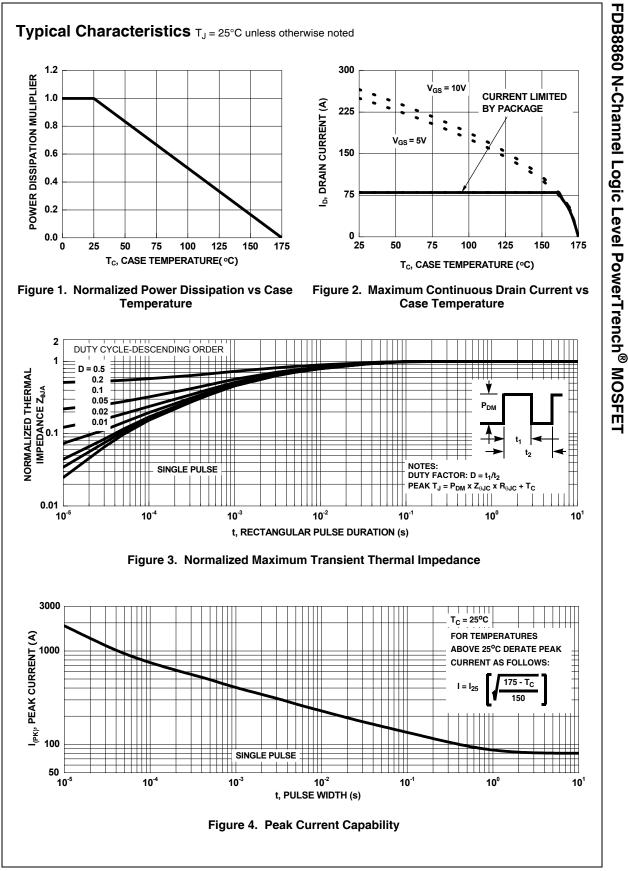
CISS	Input Capacitance			-	9460	12585	pF
C _{OSS}	Output Capacitance	── V _{DS} = 15V, V _{GS} = 0V, ── f = 1MHz		-	1710	2275	рF
C _{RSS}	Reverse Transfer Capacitance			-	1050	1575	pF
R _G	Gate Resistance	f = 1MHz		-	1.8	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0V to 10V		-	165	214	nC
Q _{g(5)}	Total Gate Charge at 5V	$V_{GS} = 0V$ to 5V	1	-	89	115	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{GS} = 0V$ to 1V	$V_{DD} = 15V$	-	9.1	12	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 80A I _a = 1.0mA	-	26	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		-g = 1.011/1	-	18	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		-	-	33	-	nC

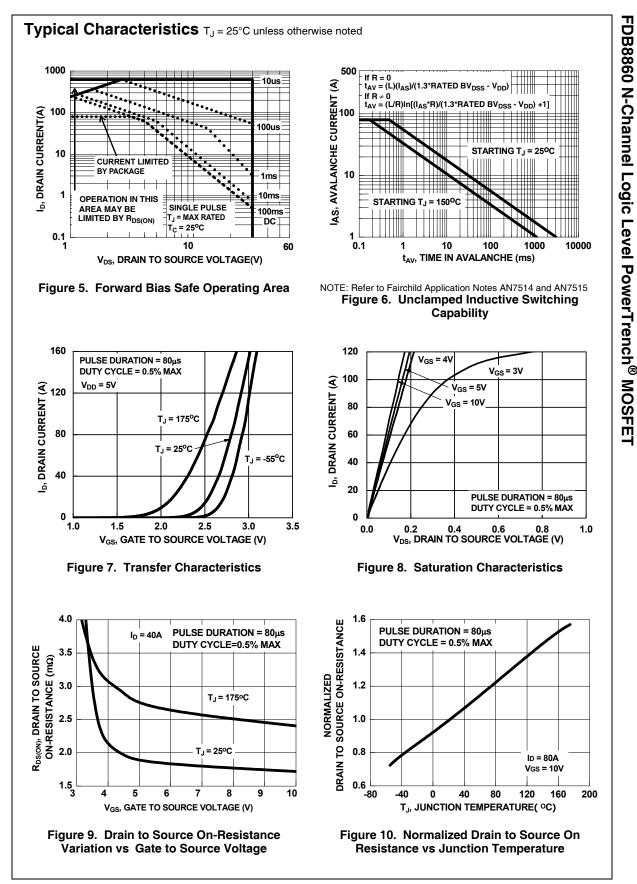
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switching	g Characteristics					
t _(on)	Turn-On Time		-	-	340	ns
t _{d(on)}	Turn-On Delay Time		-	14	-	ns
t _r	Turn-On Rise Time	V _{DD} = 15V, I _D = 80A	-	213	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 5V, R_{GS} = 1\Omega$	-	79	-	ns
t _f	Turn-Off Fall Time		-	49	-	ns
t _{off}	Turn-Off Time		-	-	192	ns

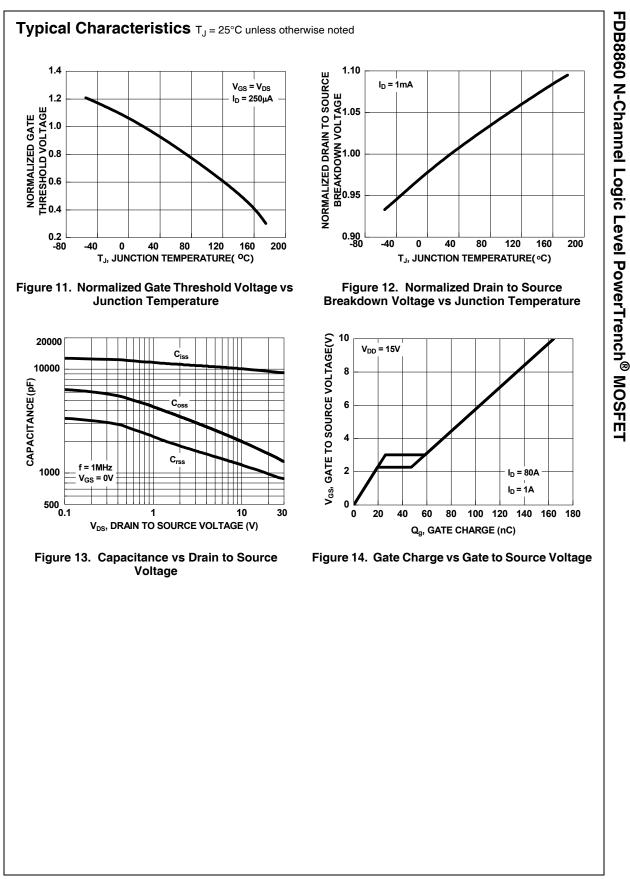
V	Source to Drain Diode Voltage	$I_{SD} = 80A$	-	-	1.25	v
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 40A	-	-	1.0	V
t _{rr}	Reverse Recovery Time	$I_{SD} = 80A$, $dI_{SD}/dt = 100A/\mu s$	-	-	43	ns
Q _{rr}	Reverse Recovery Charge	$I_{SD} = 80A$, $dI_{SD}/dt = 100A/\mu s$	-	-	29	nC

Notes: 1: Starting $T_J = 25^{\circ}$ C, L =0.47mH, I_{AS} = 64A , V_{DD} = 30V, V_{GS} = 10V. 2: Pulse width = 100s

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